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Conference on: Ultrafast Dynamics of Correlated Materials | (smr 2493)

Tuesday 15 October 2013

Resistive switching induced by an electronic avalanche phenomenon in the narrow gap Mott Insulators GaM4Q8 (M = V, Nb, Ta; Q = S, Se) - Leonardo da Vinci Building Main Lecture Hall (16:30-17:15)

time	title	presenter
16:30	Resistive switching induced by an electronic avalanche phenomenon in the narrow gap Mott Insulators GaM4Q8 (M = V, Nb, Ta; Q = S, Se)	LAURENT CARIO